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AW	US	4,314,910		1982-02-09	Barnes			i	-
W	US	5,006,908		1991-04-09	Matsuoka et al.	_			
dw	US	5,369,289		1994-11-29	Tamaki et al.			 	
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AW.	JP	59-30107	U	1984-02-24	JAPAN				х
AW	JP .	7-32638	U	1995-06-16	JAPAN			Х	
W	JP	01-257993	A	1989-10-16	JAPAN			ABS	
W.	JР	01-260707	A	1989-10-18	JAPAN			ABS	
	JР	02-111922	A	1990-04-24	JAPAN			ABS	
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9W	JР	06-82633	A	1994-03-25	JAPAN			Х	
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Da/	"White	LED lamp: Eff	icient :	light-emitting;	Manufacture cost ha	lf", N	likkei S	angyo	
CYAN	Snimbu	n, September 1	3, 1996	, Published by N	lihon Keizai Shimbur	sha.			
an	Shuji	NAKAMURA, "Ing	aN/AlGal	N blue-light-emi	tting diodes", J. V	ac. So	i. Tech	nol.	1
(V),	13 (3),	May/Jun 1995,	pp. 705	-/10.					
dw	Shuji Vol. 3	NAKAMURA et al 2 (1993), pp. 1	., "Si-I L16-L19	Doped InGaN Film Part 2, No. 1A	ns Grown on GaN Film A/B, 15 January 1993	ns", Jr	on. J. A	ppl. 1	Phys.
1./	Shuji	NAKAMURA et al	., "P-Ga	aN/N-InGaN/N-GaN	Double-Heterostruc	ture E	lue-Lig	ht-	
MN	15, Ja	nuary 1993.			32 (1993), pp. L8-L				
dw	Shuji light-	NAKAMURA, "Zn-o emitting diode:	doped Ir 3", Jour	GaN growth and chal of Crystal	InGaN/AlGaN double- Growth, 145 (1994),	pp. 9	structu 11-917. <i>Mon</i> +h	re blu	ıe-
gn	Shuji Diodes	NAKAMURA, "High ", IEDM 94 (19	n-Power 94), IEB	InGaN/AlGaN Dou EE, pp. 567-570.	no month			mittir	ıg
dw	Kozo O Journa	SAMURA et al., l of Applied Pl	"Prepai nysics,	ration and optic Vol. 46, No. 8,	al properties of Ga August 1975, pp. 3	1-xIn _x N 432-34	thin f	ilms",	
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dw	JP	07-114904	A	1995-05-02	JAPAN	_		х	
gn	JP	07-235207	A	1995-09-05	JAPAN			Х	
AW	JP	53-7153		1978-01-21	JAPAN	_			х
IN	JP	7-42152	Ų	1995-07-21	JAPAN			Х	
M	JP	55-4898	A	1980-01-14	JAPAN				х
ZW	JP	55-005533	A	1980-01-16	JAPAN			ABS	. 1
JW	JP	60-185457	A	1985-09-20	JAPAN			ABS	
gm	JP	62-20237	A	1987-01-28	JAPAN	_			Х
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AW.	G. BLA Chemic	SSE et al., "In al Physics, Vo	nvestiga l. 47, 1	ation of Some Co No. 12, 15 Decem	e ¹ -Activated Phosph mber 1967.	ors",	Journal	of	
dw	W.W. He Crysta	OLLOWAY, Jr. et ls", Physics Lo	al., etters,	*On The Fluores Vol. 25A, No.	cence of Cerium - A 8, 23 October 1967,	pp. 61	ed Garne 14-615.	t	
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an/	JP	07-120754	A	1995-05-12	JAPAN	-		х		
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No.	JP	7-99345	A	1995-04-11	JAPAN		<u> </u>	x		
an	JP	09-027642	Α	1997-01-28	JAPAN		<u> </u>	X		
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W	EP	0 541 373	A2	1992-11-05	EPO		<u> </u>			
J/W	EP	0 599 224	A1	1994-06-01	EPO		<u> </u>			
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Λ. /	"Nichi	a Chemical sta	rts the	sample shipmen	t of white light en	nitting	diode"	, News		
W	Report	, translation	of page	15 of Nikkei E	lectronics 1996.9.2	23 (No.	671).			
	"Proce	edings of the	Institut	e of Phosphor	Society", Translat:	ion of	pages 1	, 5 to	14	
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AW	US	4,727,283		1988-02-23	van Kemenade et al	_			
W	US	4,298,820		1981-11-03	Bongers et al.				
ЯW	ບຣ	3,699,478		1972-10-17	Pinnow et al.				
AW	US	5,798,537		1998-08-25	Nitta	_			
W.	US	5,202,777		1993-04-13	Sluzky et al.				
2W		3,819,974		1974-06-25	Stevenson et al.				
W	·US	5,847,507		1998-12-08	Butterworth et al.				
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1	JP	NUMBER 01179471	A	1989-07-17	JAPAN			ABS	ON
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 	JP	554898	A	1980-01-14	JAPAN				
	JP	09027642	A	1997-01-28	JAPAN			ABS	
	JP	08007614	A	1996-01-12	JAPAN	-		ABS	
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	JP	07099345	A	1995-04-11	JAPAN			ABS	
	JP	05152609	A	1993-06-18	JAPAN			ABS	
	JP	6220237	A	1987-01-28	JAPAN				
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dw	Nakamu	ra, SPIE, Vol.	3002,]	pp. 26-35 (1997	no month				
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AW	US	4,550,256		1985-10-29	Berkstesser et al.					
AN	US	4,716,337		1987-12-29	Huiskes et al.	-				
AW	US	5,471,113		1995-11-28	De Backer et al.					
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DW	MO	9750132	A1	1997-12-31	PCT	-	_			
9W	WO	9812757	A1	1998-03-26	PCT		_			
W.	JР	5079379		1973-11-24	JAPAN		<u></u>	ABS		
XW	JP	742152		1995-07-21	JAPAN			ABS		
W/	JР	4717684		1972-09-09	JAPAN	}		Х		
SW	JP	491221		1974-01-12	JAPAN	_		Х		
WW.	JP	49112577		1974-10-26	JAPAN	_		ABS		
W	JP	62189770		1986-02-15	JAPAN	_		ABS		
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BW				rths, A New Era sics, 16 pp. 28	in Fluorescent Ligh 3-299 (1987) NO M		, B.M.J	. Smet	9,	
BW	"A New Emitti	Phosphor for ng", G. Blas	Flying- se et a	Spot Cathode-Ra l., App. Phys.	y Tubes for Color To Lett. Vol. 11, No. 2	2, pp.	ion: Ye. 53-55 monfh	llow (1967)		
AW				GINEERING, "Hig . 38, No. 7, pp	h-intensity White Ba . 55-58	acklig	hting fo	or LCD	of	
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	GB	1589964		1981-05-20	GREAT BRITAIN	ļ <u> </u>		ABS	
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W	JP	563068		1993-08-20	JAPAN			ABS	
VIIV	JP	8170077		1996-07-02	JAPAN			ABS	
KIN	JP	5331584		1978-03-24	JAPAN				
AW	JP	60144381		1985-07-30	JAPAN			ABS	
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AW	JP.	6208845		1994-07-26	JAPAN			ABS	
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